

MS1406

MS1406 Information

Heisener.com	Part Number Manufacturer Category Description Package	MS1406 Microsemi Corporation Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS RF BIPO 30W 3A M135 M135 For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

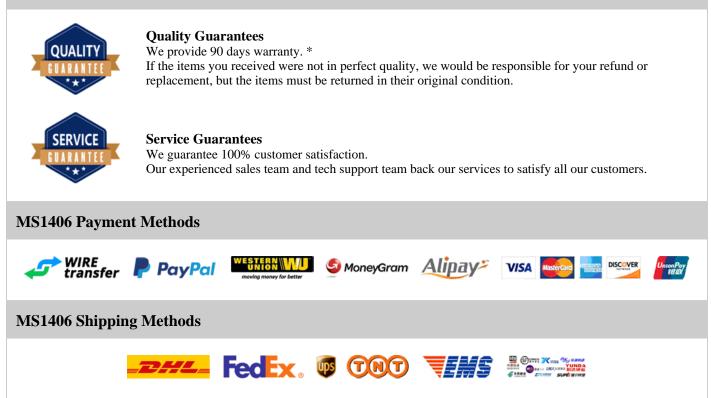
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MS1406 Specifications

Manufacturer Part Number	MS1406
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	M135
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	35V
Frequency - Transition	175MHz
Noise Figure (dB Typ @ f)	-
Gain	8.2dB
Power - Max	30W
DC Current Gain (hFE) (Min) @ Ic, Vce	10 @ 200mA, 5V
Current - Collector (Ic) (Max)	3A
Operating Temperature	200°C (TJ)
Mounting Type	Chassis, Stud Mount
Package / Case	M135
Supplier Device Package	M135
	Report errors?

MS1406 Guarantees



If you have any question about MS1406, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com